IN THE UNITED STATES PATENT AND EMARK OFFICE

In re PATENT APPLICATION of

MANARE et al

Divisional of Appln. No. 09/379,621

Group Art Unit: 2811

Filed: Herewith

Examiner: M. Tran

Title: LIGHT-EMITTING SEMICONDUCTOR

DEVICE USING GROUP III NITRIDE COMPOUND (AS AMENDED)

February 15, 2001

PRELIMINARY AMENDMENT

Hon. Commissioner of Patents Washington, D.C.

Dear Sir:

Prior to the examination, please amend the above-identified application as follows:

IN THE TITLE:

Please change the title of the invention to --LIGHT-EMITTING ALUMINUM GALLIUM INDIUM NITRIDE COMPOUND SEMICONDUCTOR DEVICE HAVING AN IMPROVED LUMINOUS INTENSITY--.

IN THE CLAIMS:

Please cancel claims 1-15 without prejudice or disclaimer.

Please add new claims 16 and 17 as follows:

--16. A method for producing a light-emitting semiconductor device, said method comprising:

forming a substrate;

forming a buffer layer on said substrate;

forming an N-layer of N-type nitrogen-III Group compound semiconductor satisfying the

formula A1xGayIn1-x-yN, inclusive of x=0, y=0 and; x= y=0;